

74LVT273

3.3 V octal D-type flip-flop

Rev. 03 — 10 September 2008

Product data sheet

1. General description

The 74LVT273 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3 V.

This device has eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) and Master Reset ($\overline{MR}$) inputs load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced LOW independent of the clock or data inputs by a LOW voltage level on the $\overline{MR}$ input. The device is useful for applications where only the true output is required and the CP and $\overline{MR}$ are common elements.

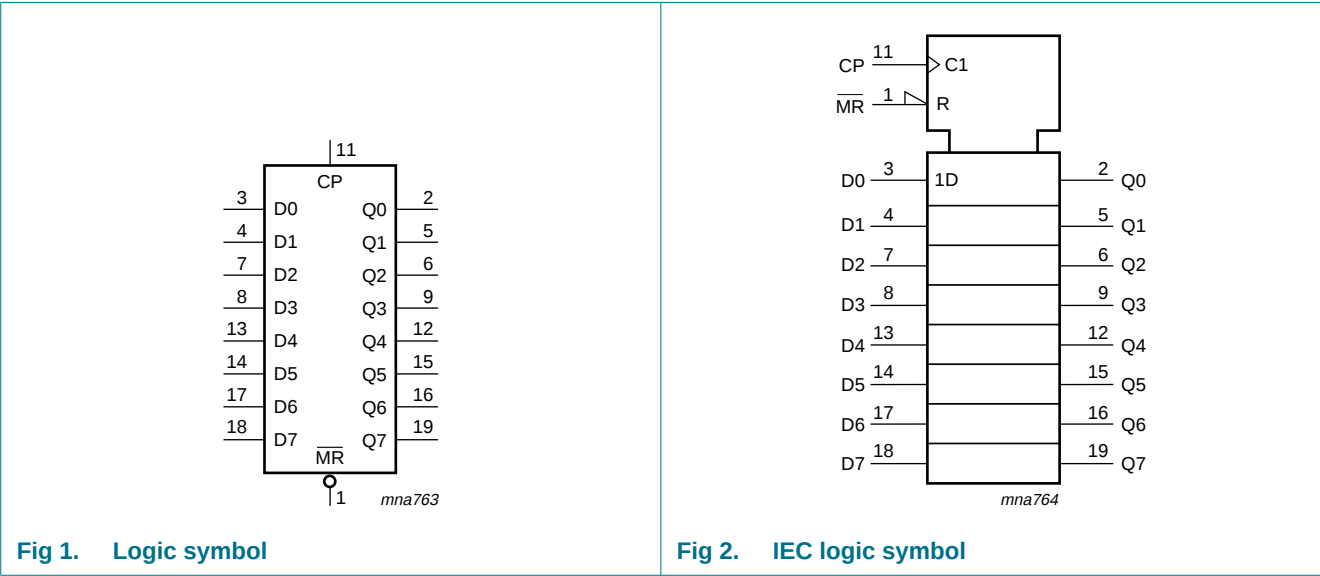
2. Features

- Eight edge-triggered D-type flip-flops
- Buffered common clock and asynchronous master reset
- Input and output interface capability to systems at 5 V supply
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Output capability: +64 mA/–32 mA
- Latch-up protection
 - ◆ JESD78 Class II exceeds 500 mA
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
- Bus-hold data inputs eliminate the need for external pull-up resistors for unused inputs
- Live insertion/extraction permitted
- Power-up reset
- No bus current loading when output is tied to 5 V bus

3. Ordering information

Table 1. Ordering information				
Type number	Package			
	Temperature range	Name	Description	Version
74LVT273D	−40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74LVT273DB	−40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74LVT273PW	−40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74LVT273BQ	−40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1

4. Functional diagram



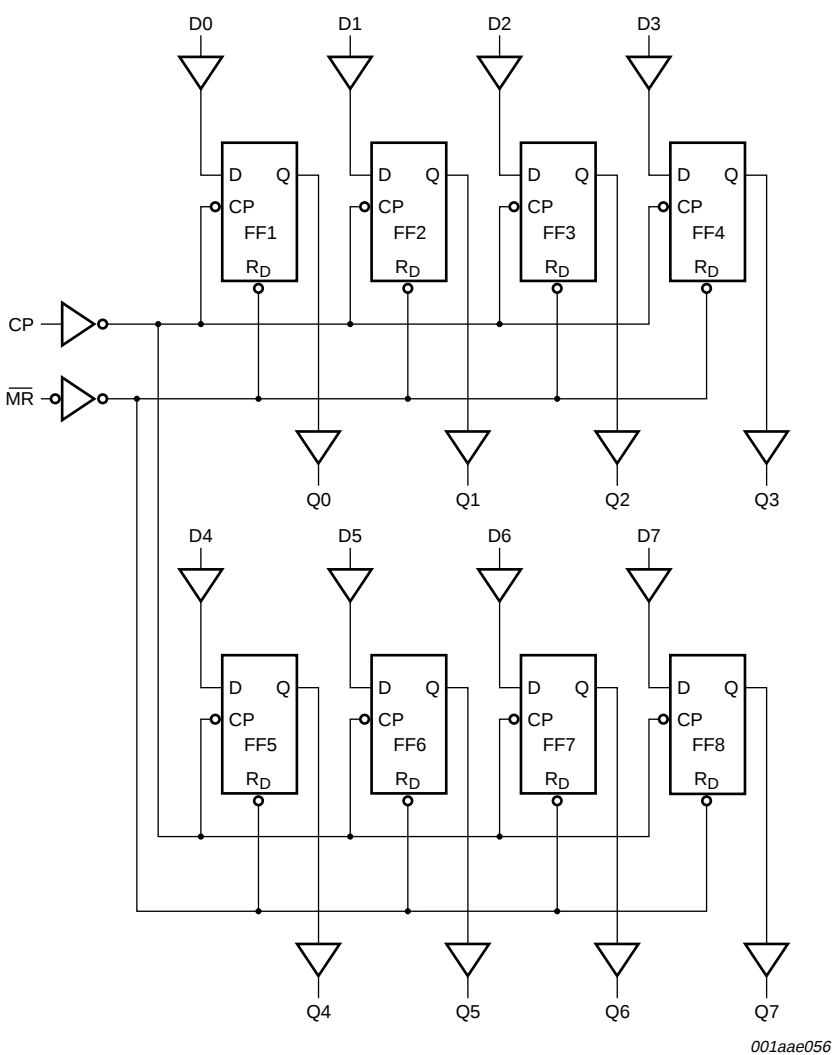
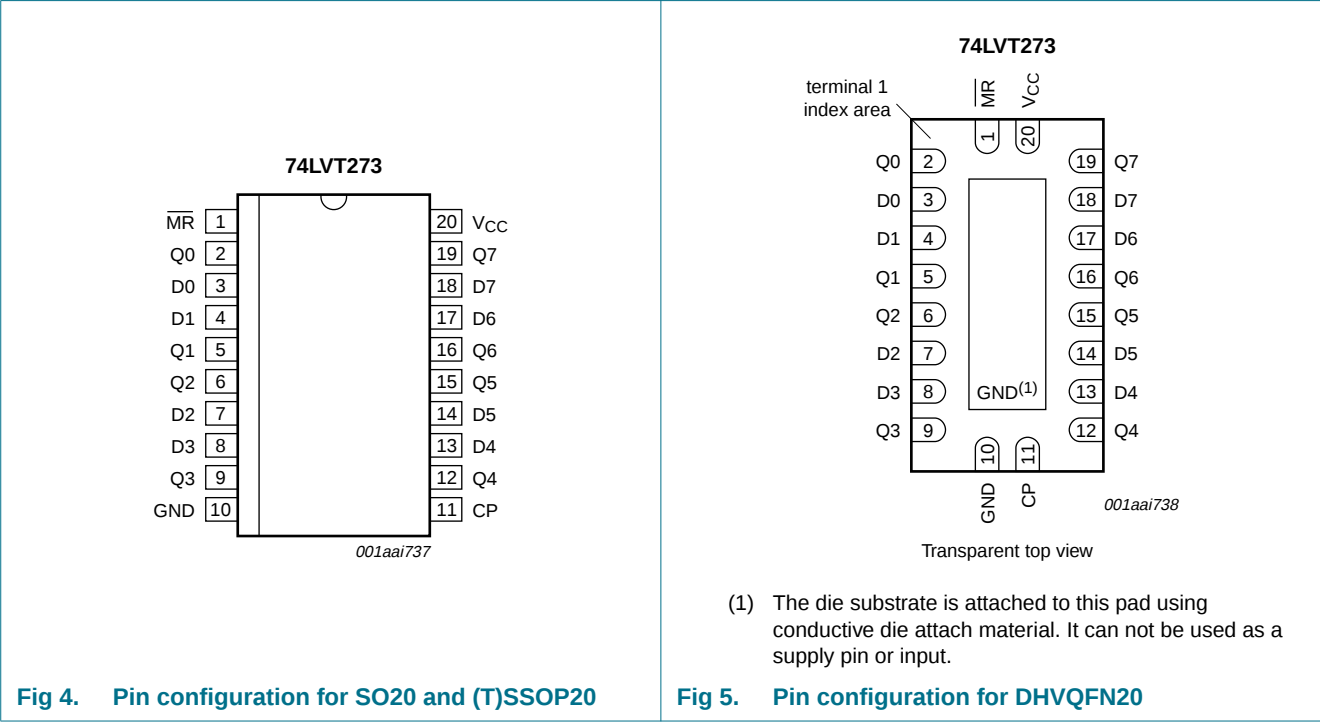


Fig 3. Logic diagram

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
MR	1	master reset input (active LOW)
Q0 to Q7	2, 5, 6, 9, 12, 15, 16, 19	data output
D0 to D7	3, 4, 7, 8, 13, 14, 17, 18	data input
GND	10	ground (0 V)
CP	11	clock pulse input (active on rising edge)
VCC	20	positive supply voltage

6. Functional description

Table 3. Function selection

Inputs			Outputs	Operating mode
MR	CP	Dn	Qn	
L	X	X	L	Reset (clear)
H	↑	h	H	Load 1
H	↑	l	L	Load 0
H	L	X	Q0	Retain state

- [1] H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the prior to the LOW-to-HIGH clock transition;
 L = LOW voltage level; l = LOW voltage level one set-up time prior to the prior to the LOW-to-HIGH clock transition;
 X = Don't care; ↑ = LOW-to-HIGH clock transition; Q0 = output as it was.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		−0.5	+4.6	V
V _I	input voltage		[1] −0.5	+7.0	V
V _O	output voltage	Output in OFF or HIGH state	[1] −0.5	+7.0	V
I _{IK}	input clamping current	V _I < 0 V	−50	-	mA
I _{OK}	output clamping current	V _O < 0 V	−50	-	mA
I _O	output current	output in LOW state	-	128	mA
		output in HIGH state	−64	-	mA
T _{stg}	storage temperature		−65	+150	°C
T _j	junction temperature		[2] -	150	°C
P _{tot}	total power dissipation	T _{amb} = −40 °C to +85 °C	[3]	500	mW

- [1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
 [2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.
 [3] For SO20 packages: above 70 °C derate linearly with 8 mW/K.
 For SSOP20 and TSSOP20 packages: above 60 °C derate linearly with 5.5 mW/K.
 For DHVQFN20 packages: above 60 °C derate linearly with 4.5 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{CC}	supply voltage		2.7	-	3.6	V
V _I	input voltage		0	-	5.5	V
I _{OH}	HIGH-level output current		−32	-	-	mA

Table 5. Recommended operating conditions ...continued

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{OL}	LOW-level output current		-	-	64	mA
T_{amb}	ambient temperature	in free air	-40	-	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate; output enabled		-	-	10	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			Unit
			Min	Typ ^[1]	Max	
V_{IK}	input clamping voltage	$V_{CC} = 2.7\text{ V}; I_{IK} = -18\text{ mA}$	-1.2	-0.9	-	V
V_{IH}	HIGH-level input voltage		2.0	-	-	V
V_{IL}	LOW-level input voltage		-	-	0.8	V
V_{OH}	HIGH-level output voltage	$V_{CC} = 2.7\text{ V to } 3.6\text{ V}; I_{OH} = -100\text{ }\mu\text{A}$	$V_{CC} - 0.2$	$V_{CC} - 0.1$	-	V
		$V_{CC} = 2.7\text{ V}; I_{OH} = -8\text{ mA}$	2.4	2.5	-	V
		$V_{CC} = 3.0\text{ V}; I_{OH} = -32\text{ mA}$	2.0	2.2	-	V
V_{OL}	LOW-level output voltage	$V_{CC} = 2.7\text{ V}; I_{OL} = 100\text{ }\mu\text{A}$		0.1	0.2	V
		$V_{CC} = 2.7\text{ V}; I_{OL} = 24\text{ mA}$	-	0.3	0.5	V
		$V_{CC} = 3.0\text{ V}; I_{OL} = 16\text{ mA}$	-	0.25	0.4	V
		$V_{CC} = 3.0\text{ V}; I_{OL} = 32\text{ mA}$	-	0.3	0.5	V
		$V_{CC} = 3.0\text{ V}; I_{OL} = 64\text{ mA}$	-	0.4	0.55	V
$V_{OL(pu)}$	power-up LOW-level output voltage	$V_{CC} = 3.6\text{ V}; I_O = 1\text{ mA}; V_I = \text{GND or } V_{CC}$ [2]	-	0.13	0.55	V
I_I	input leakage current	input pins				
		$V_{CC} = 0\text{ V or } 3.6\text{ V}; V_I = 5.5\text{ V}$	-	1	10	μA
		control pins				
		$V_{CC} = 3.6\text{ V}; V_I = V_{CC} \text{ or } \text{GND}$	-	± 0.1	± 1	μA
		data pins [3]				
		$V_{CC} = 3.6\text{ V}; V_I = V_{CC}$	-	0.1	1	μA
I_{OFF}	power-off leakage current	$V_{CC} = 0\text{ V}; V_I \text{ or } V_O = 0\text{ V to } 4.5\text{ V}$	-	1	± 100	μA
		$V_{CC} = 3.0\text{ V}; V_O = 5.5\text{ V}; \text{output HIGH}$	-	60	125	μA
I_{BHL}	bus hold LOW current	$V_{CC} = 3.0\text{ V}; V_I = 0.8\text{ V}$ [4]	75	150	-	μA
I_{BHH}	bus hold HIGH current	$V_{CC} = 3.0\text{ V}; V_I = 2.0\text{ V}$	-	-150	-75	μA
I_{BHHO}	bus hold HIGH overdrive current	$V_{CC} = 3.6\text{ V}; V_I = 0\text{ V to } 3.6\text{ V}$	-	-	500	μA
I_{BHLO}	bus hold LOW overdrive current	$V_{CC} = 3.6\text{ V}; V_I = 0\text{ V to } 3.6\text{ V}$	-500	-	-	μA

Table 6. Static characteristics ...continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	–40 °C to +85 °C			Unit
			Min	Typ ^[1]	Max	
I _{CC}	supply current	V _{CC} = 3.6 V; V _I = V _{CC} or GND; I _O = 0 A				
		outputs HIGH	-	0.13	0.19	mA
		outputs LOW	-	3	12	mA
ΔI _{CC}	additional supply current	per input pin; V _{CC} = 3.0 V to 3.6 V; one input = V _{CC} – 0.6 V; other inputs at V _{CC} or GND ^[5]	-	0.1	0.2	mA
C _I	input capacitance	V _I = 0 V or 3.0 V	-	4	-	pF

[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

[2] For valid test results data must not be loaded into the flip-flops (or latches) after applying the power.

[3] Unused pins at V_{CC} or GND.

[4] This is the bus hold overdrive current required to force the input to the opposite logic state.

[5] Increase in supply current for each input at the specified voltage level other than V_{CC} or GND

10. Dynamic characteristics

Table 7. Dynamic characteristicsVoltages are referenced to GND (ground = 0 V). For test circuit see [Figure 9](#).

Symbol	Parameter	Conditions	–40 °C to +85 °C			Unit
			Min	Typ ^[1]	Max	
t _{PLH}	LOW to HIGH propagation delay	CP to Qn; Figure 6				
		V _{CC} = 2.7 V	-	-	6.3	ns
		V _{CC} = 3.3 V ± 0.3 V	1.7	3.5	5.5	ns
t _{PHL}	HIGH to LOW propagation delay	CP to Qn; Figure 6				
		V _{CC} = 2.7 V	-	-	5.9	ns
		V _{CC} = 3.3 V ± 0.3 V	1.9	3.5	5.5	ns
		MR to Qn; see Figure 7				
		V _{CC} = 2.7 V	-	-	6.2	ns
		V _{CC} = 3.3 V ± 0.3 V	1.3	3.2	6.2	ns
t _{su}	set-up time	Dn to CP HIGH; see Figure 7 ^[2]				
		V _{CC} = 2.7 V	2.7	-	-	ns
		V _{CC} = 3.3 V ± 0.3 V	2.3	1.0	-	ns
		Dn to CP LOW; see Figure 7				
		V _{CC} = 2.7 V	2.7	-	-	ns
		V _{CC} = 3.3 V ± 0.3 V	2.3	1.0	-	ns
t _h	hold time	Dn to CP HIGH; see Figure 8 ^[3]				
		V _{CC} = 2.7 V	0	-	-	ns
		V _{CC} = 3.3 V ± 0.3 V	0	-0.6	-	ns
		Dn to CP LOW; see Figure 8				
		V _{CC} = 2.7 V	0	-	-	ns
		V _{CC} = 3.3 V ± 0.3 V	0	-0.6	-	ns

Table 7. Dynamic characteristics ...continued
Voltages are referenced to GND (ground = 0 V). For test circuit see [Figure 9](#).

Symbol	Parameter	Conditions	–40 °C to +85 °C			Unit
			Min	Typ ^[1]	Max	
t _W	pulse width	CP input HIGH or LOW; see Figure 6 ^[4]				
		V _{CC} = 2.7 V	3.3	-	-	ns
		V _{CC} = 3.3 V ± 0.3 V	3.3	1.5	-	ns
		MR input LOW; see Figure 7				
		V _{CC} = 2.7 V	3.3	-	-	ns
		V _{CC} = 3.3 V ± 0.3 V	3.3	1.5	-	ns
t _{rec}	recovery time	see Figure 7				
		V _{CC} = 2.7 V	3.2	-	-	ns
		V _{CC} = 3.3 V ± 0.3 V	2.7	1.0	-	ns
f _{max}	maximum frequency	CP input; see Figure 7	150	-	-	MHz

- [1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 3.3 V
[2] t_{SU} is the same as t_{SU(L)} and t_{SU(H)}
[3] t_H is the same as t_{H(L)} and t_{H(H)}
[4] t_W is the same as t_{WL} and t_{WH}

11. Waveforms

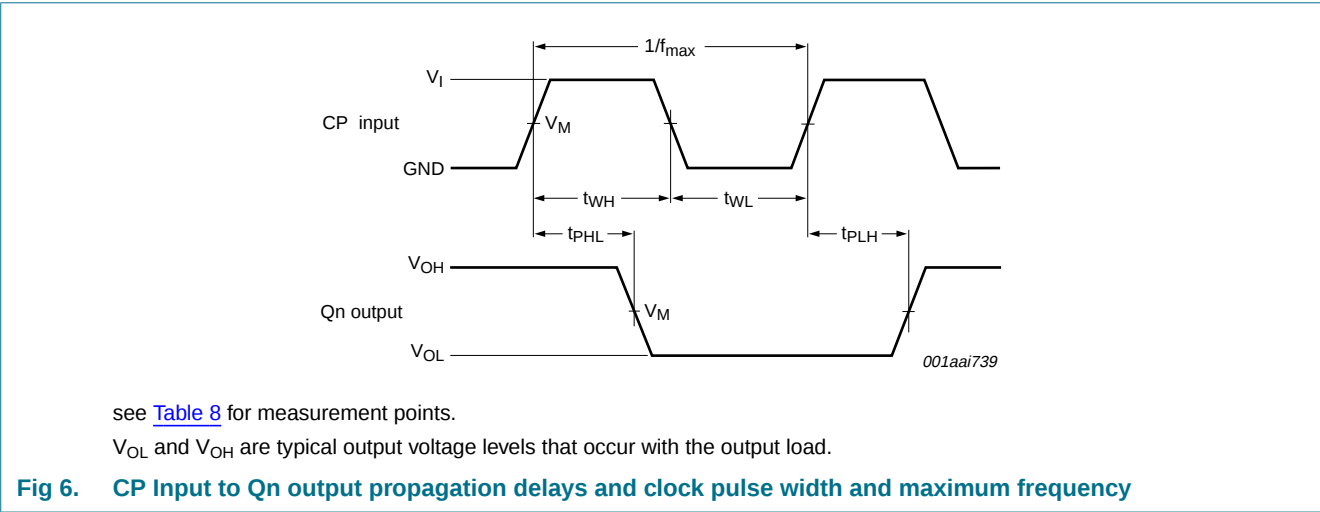
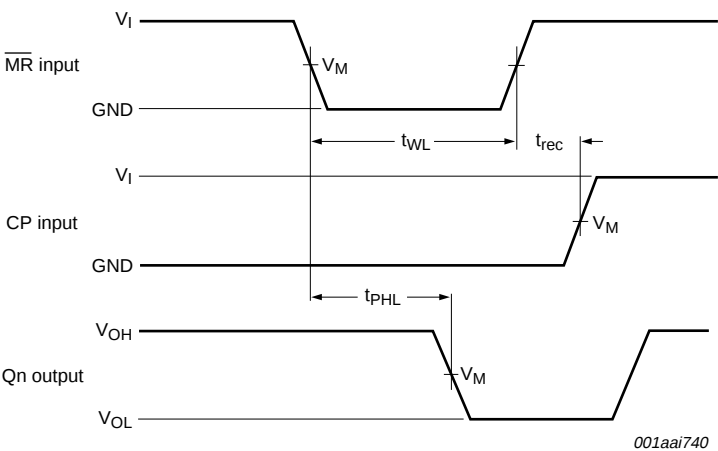


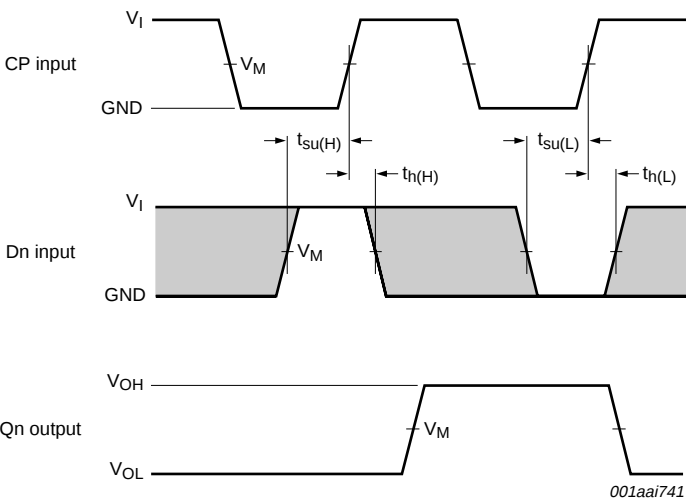
Table 8. Measurement points

Input		Output
V _I	V _M	V _M
2.7 V	1.5 V	1.5 V



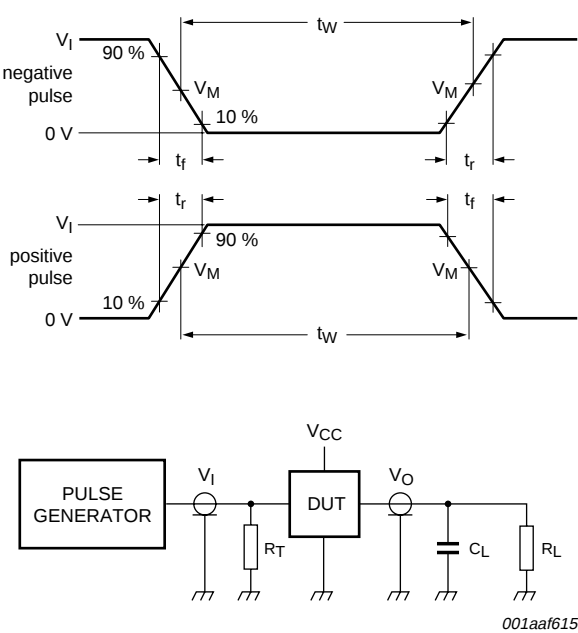
see [Table 8](#) for measurement points.
 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 7. $\overline{MR}$ pulse width, $\overline{MR}$ to CP recovery time and $\overline{MR}$ to Qn delay



see [Table 8](#) for measurement points.
 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.
The shaded areas indicate when the input is permitted to change for predictable output performance.

Fig 8. Data set-up and hold times



Test data is given in given in [Table 9](#).
Definitions for test circuit:
 R_L = Load resistance;
 C_L = Load capacitance including jig and probe capacitance;
 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

Fig 9. Load circuitry for switching times

Table 9. Test data

Input				Load	
V_I	Repetition rate	t_W	t_r, t_f	R_L	C_L
2.7 V	≤ 10 MHz	500 ns	≤ 2.5 ns	500 Ω	50 pF

12. Package outline

SO20: plastic small outline package; 20 leads; body width 7.5 mm SOT163-1

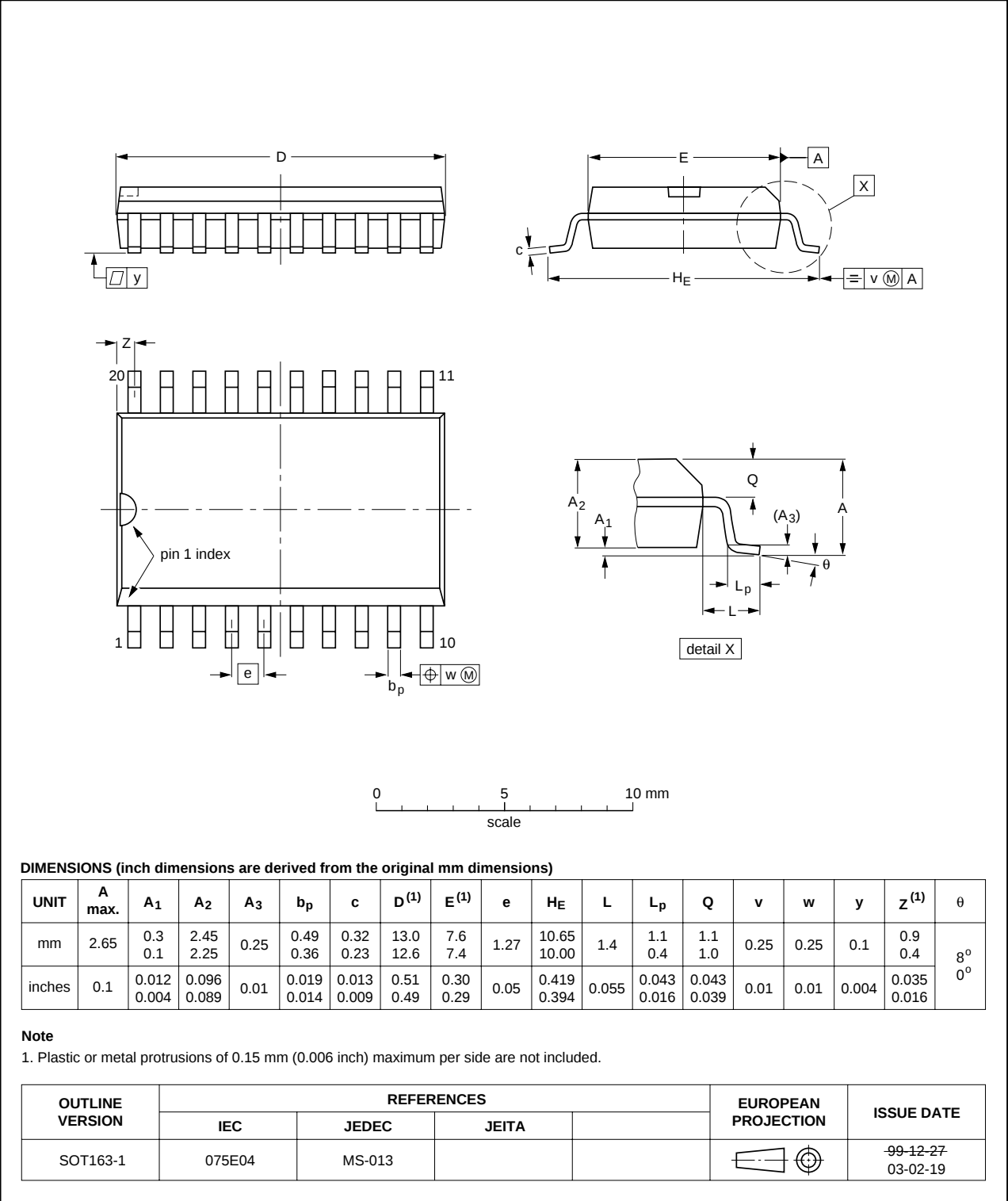


Fig 10. Package outline SOT163-1 (SO20)

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1

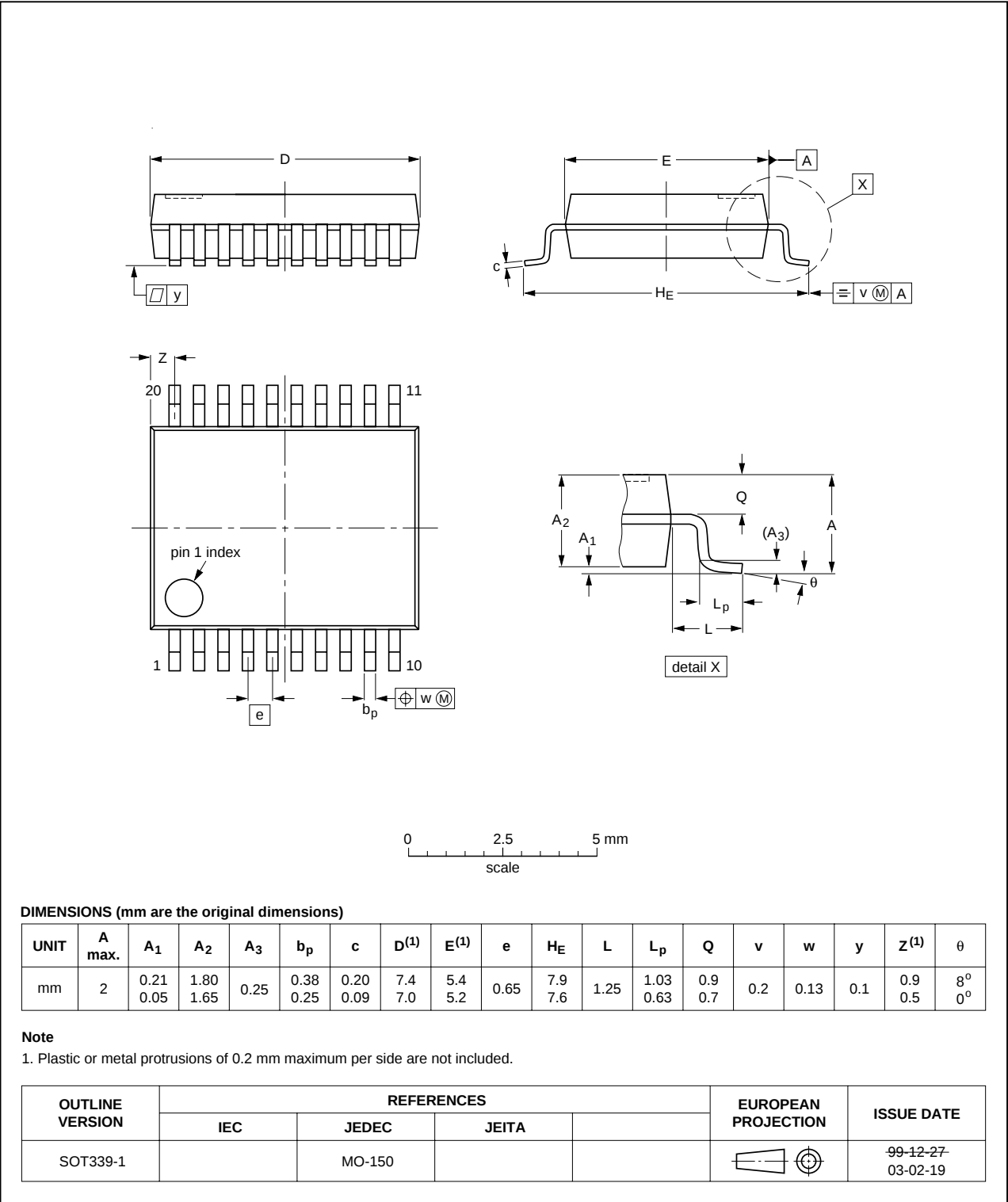


Fig 11. Package outline SOT339-1 (SSOP20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

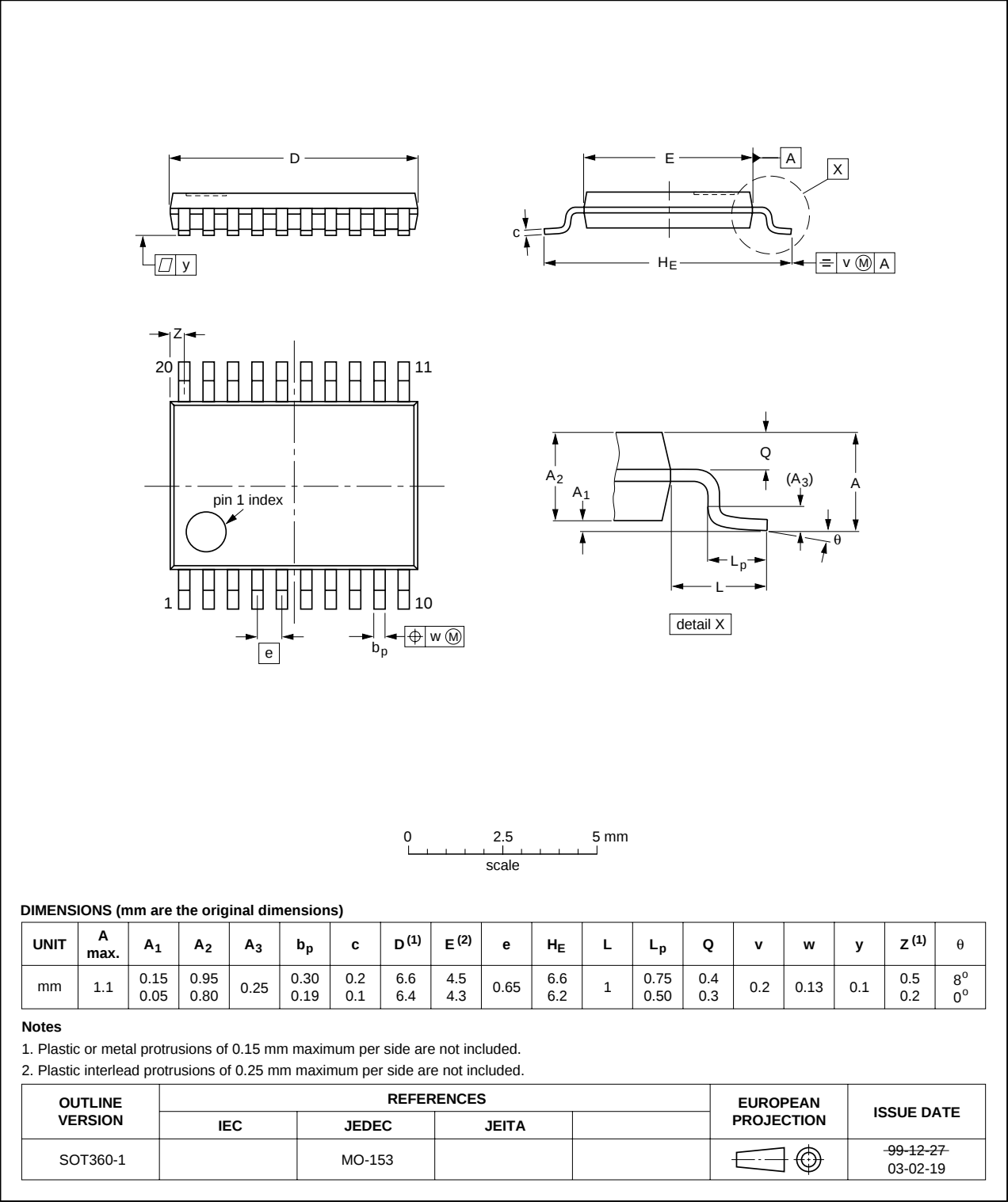


Fig 12. Package outline SOT360-1 (TSSOP20)

DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads;
20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

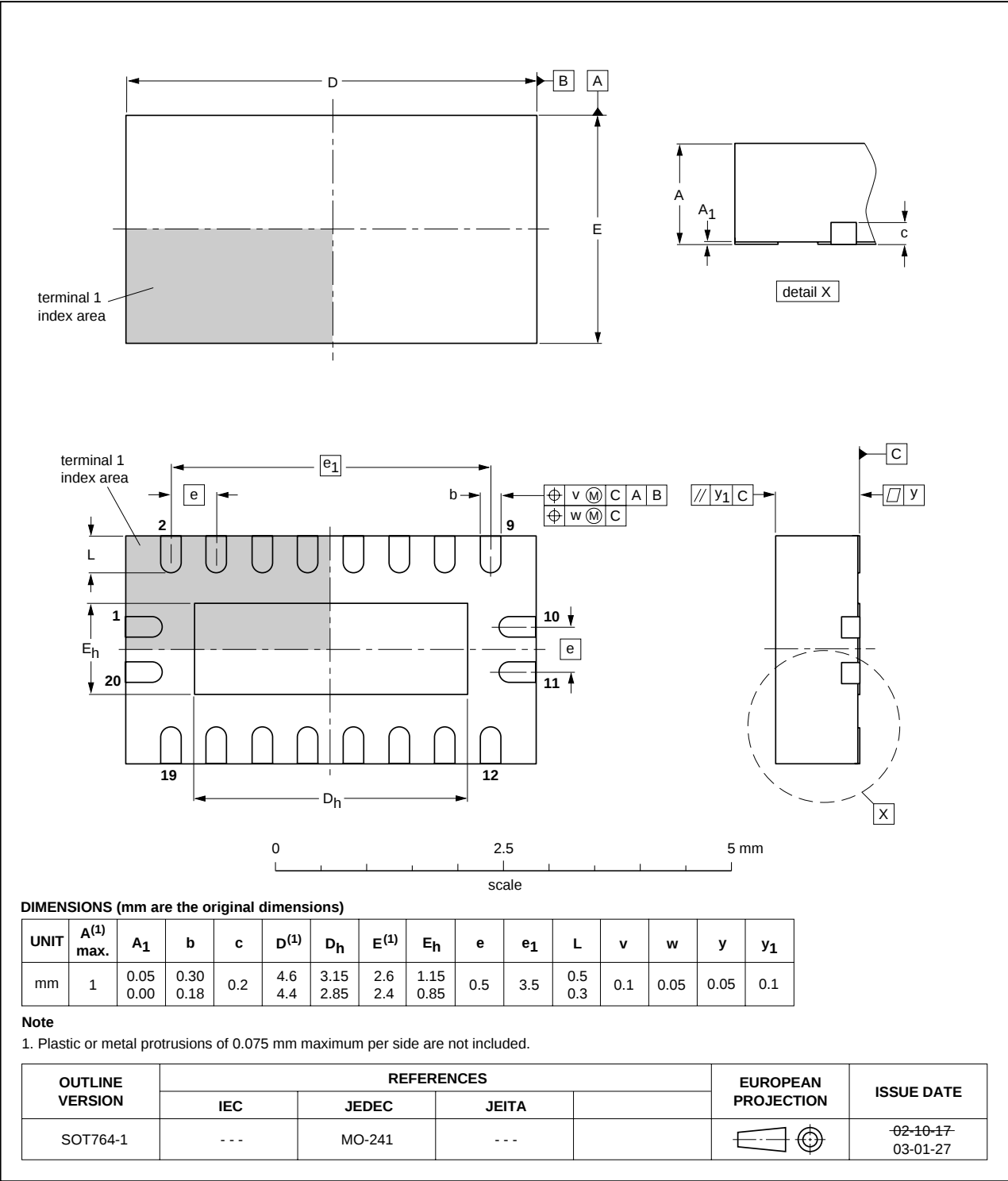


Fig 13. Package outline SOT764-1 (DHVQFN20)

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
BICMOS	Integrated Bipolar junction transistors and CMOS
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVT273_3	20080910	Product data sheet	-	74LVT273_2
Modifications:	• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. • Legal texts have been adapted to the new company name where appropriate. • Title changed to 3.3 V octal D-type flip-flop • Section 3 “Ordering information” and Section 12 “Package outline” DHVQFN20 package added. • Table 4 “Limiting values” T_J and P_{tot} values added.			
74LVT273_2	19980219	Product specification	-	-

15. Legal information

16. Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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